

Description

The AU3361P0 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time, very low capacitance and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The AU3361P0 complies with the IEC 61000-4-2 (ESD) with ±30kV air and ±28kV contact discharge. It is assembled into an ultra-small 0.6×0.3×0.3mm lead-free DFN package. The small size and very low capacitance make AU3361P0 an ideal choice to protect cell phone, digital cameras, audio players, data interface and many other portable applications.

Features

- Ultra small package: 0.6x0.3x0.3mm
- Protects one data or power line
- Very low capacitance: 3pF typical
- Ultra low leakage: nA level
- Operating voltage: 3.3V
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 Air discharge: ±30kV
 Contact discharge: ±28kV
- RoHS compliant

Mechanical Characteristics

- Package: DFN0603-2 (0.6×0.3×0.3mm)
- Lead Finish: NiPdAu
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

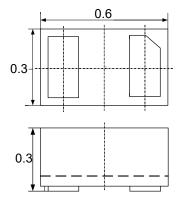
- Cellular Handsets and Accessories
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- Audio Players
- Keypads, Side Keys, USB, LCD Displays

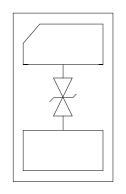
Marking Information



Z3 = Device Marking Code Dot denotes pin1

Dimensions and Pin Configuration





Package Dimensions (mm)

Circuit and Pin Schematic

Ordering Information

Part Number	Packaging	Reel Size		
AU3361P0	10000/Tape & Reel	7 inch		



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

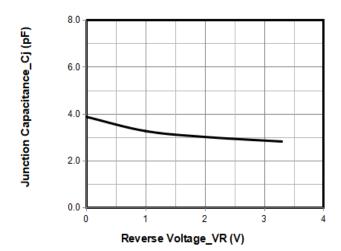
Parameter	Symbol	Value	Unit	
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV	
ESD per IEC 61000-4-2 (Contact)	VESD	±28		
Operating Temperature Range	TJ	−55 to +125	°C	
Storage Temperature Range	Tstg	−55 to +150	°C	

Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			3.3	V	Pin 1 to Pin 2 or Pin 2 to Pin 1
Breakdown Voltage	VBR	4.3			V	IT = 1mA, Pin 1 to Pin 2 or Pin 1 to Pin 2
Reverse Leakage Current	I _R			0.2	μA	VRWM = 5V, Pin 1 to Pin 2 or Pin 1 to Pin 2
Clamping Voltage	Vc			10	V	IPP = $3A (8 \times 20\mu s \text{ pulse})$, Pin 1 to Pin 2 or Pin 1 to Pin 2
Junction Capacitance	CJ		3		pF	VR = 0V, f = 1MHz

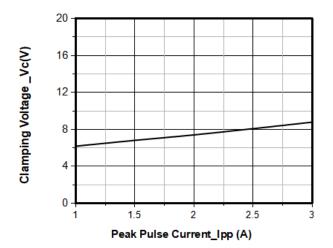


AU3361P0

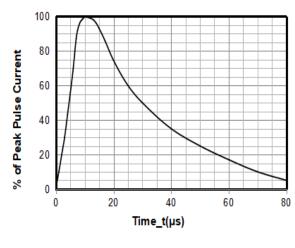


Typical Performance Characteristics (T_A=25°C unless otherwise Specified)

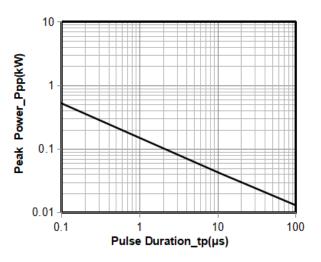
Junction Capacitance vs. Reverse Voltage



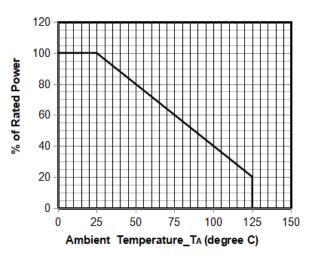
Clamping Voltage vs. Peak Pulse Current



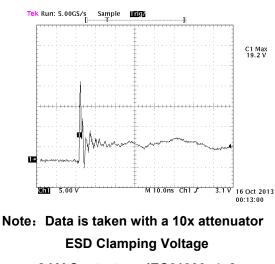
8 X 20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time

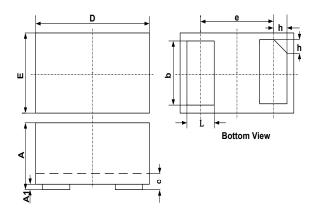


Power Derating Curve



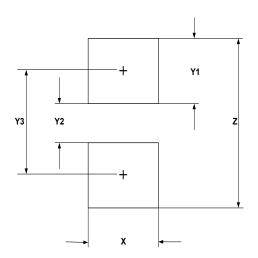


DFN0603-2 Package Outline Drawing



	DIMENSIONS					
	MILLIMETERS					
SYM	MIN	NOM		MAX		
А	0.230		0.330			
A1	0.000	0.020		0.050		
b	0.215	0.245	0.245 0.275			
С	0.120	0.150		0.180		
D	0.550	0.600	0.650			
е		0.355 BSC				
Е	0.250	0.300		0.350		
L	0.160	0.190		0.220		
h		0.079 BSC				

Suggested Land Pattern



DIMENSIONS SYM MILLIMETERS INCHES Х 0.30 0.012 Y1 0.25 0.010 Y2 0.006 0.15 Y3 0.40 0.016 Ζ 0.65 0.026

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